

Operational Amplifiers

SIGNATURE SERIES Operational Amplifiers

LM358xxx LM324xxx LM2904xxx LM2902xxx

General Description

LM358xxx, LM324xxx, LM2904xxx, and LM2902xxx are monolithic IC's which integrate two or four independent op-amps on a single chip and feature high gain, low power consumption, and an operating voltage range of 3V to 36V (single power supply).

Features

- Operable with a single power supply
- Wide operating supply voltage range
- Input and output are operable GND sense
- Low supply current
- High open loop voltage gain
- Wide temperature range

Application

- Current sense application
- Buffer application
- Active filter
- Consumer electronics

Pin Configuration

SO Package8 : LM358DT (SOP-J8) : LM358WDT : LM2904DT

: LM2904WDT

TSSOP8 : LM358PT (TSSOP-B8) : LM358WPT : LM2904PT

: LM2904WPT Mini SO8 : LM358ST (TSSOP-B8J) : LM2904ST

Key Specifications

■ Operating Supply Voltage
Single Supply +3V to +36V

Dual Supply ±1.5V to ±18V

■ Supply Current LM358xxx/LM324xxx

 LM358xxx/LM324xxx
 0.7mA(Typ)

 LM2904xxx/LM2902xxx
 0.7mA(Typ)

 Input Bias Current
 20nA(Typ)

 Input Offset Current
 2nA(Typ)

■ Operating Temperature Range

LM358xxx/LM324xxx -40°C to +85°C LM2904xxx/LM2902xxx -40°C to +125°C

Packages W(Typ) x D(Typ) x H(Max)

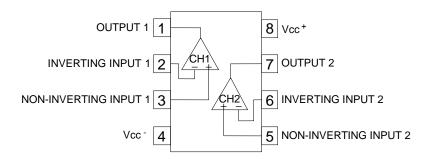
 SO Package8
 4.90mm x 6.0mm x 1.55mm

 SO Package14
 8.65mm x 6.0mm x 1.55mm

 TSSOP8
 3.00mm x 6.4mm x 1.10mm

 TSSOP14
 5.00mm x 6.4mm x 1.10mm

 Mini SO8
 3.00mm x 4.9mm x 0.95mm

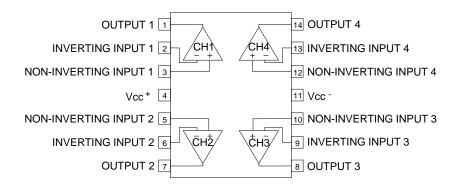


Pin Description

Pin No.	Pin Name	Function				
1	OUTPUT 1	CH1 OUTPUT				
2	INVERTING INPUT 1	CH1 INVERTING INPUT				
3	NON-INVERTING INPUT 1	CH1 NON-INVERTING INPUT				
4	Vcc ⁻	Negative power supply				
5	NON-INVERTING INPUT 2	CH2 NON-INVERTING INPUT				
6	INVERTING INPUT 2	CH2 INVERTING INPUT				
7	OUTPUT 2	CH2 OUTPUT				
8	Vcc ⁺	Positive power supply				

SO Package14 : LM324DT (SOP-J14) : LM324WDT : LM2902DT : LM2902WDT

TSSOP14 : LM324PT (TSSOP-B14J) : LM2902PT



Pin Description

Pin No.	Pin Name	Function					
1	OUTPUT1	CH1 OUTPUT					
2	INVERTING INPUT 1	CH1 INVERTING INPUT					
3	NON-INVERTING INPUT 1	CH1 NON-INVERTING INPUT					
4	Vcc ⁺	Positive power supply					
5	NON-INVERTING INPUT 2	CH2 NON-INVERTING INPUT					
6	INVERTING INPUT 2	CH2 INVERTING INPUT					
7	OUTPUT 2	CH2 OUTPUT					
8	OUTPUT3	CH3 OUTPUT					
9	INVERTING INPUT 3	CH3 INVERTING INPUT					
10	NON-INVERTING INPUT 3	CH3 NON-INVERTING INPUT					
11	Vcc ⁻	Negative power supply					
12	NON-INVERTING INPUT 4	CH4 NON-INVERTING INPUT					
13	INVERTING INPUT 4	CH4 INVERTING INPUT					
14	OUTPUT 4	CH4 OUTPUT					

Circuit Diagram

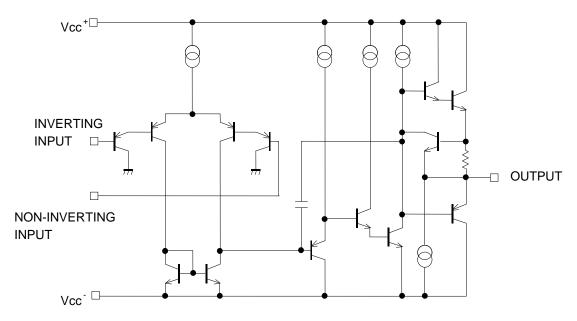


Figure 1 Circuit Diagram (each Op-Amp)

Absolute Maximum Ratings (Ta=25°C)

DSOlute Maximum Natings (, 0,							
Parameter	Symbol		Rating						
Farameter			LM358xxx	LM324xxx	LM2904xxx	LM2902xxx	Unit		
Supply Voltage		Vcc ⁺ -Vcc ⁻		+:	0.67 (Note 1,6)		V		
		SO Package8	0.67 (Note 1,6)	-	-				
		TSSOP8	0.62 (Note 2,6)	-	0.62 (Note 2,6)	-			
Power Dissipation	Pd	Mini SO8	0.58 (Note 3,6)	-	0.58 (Note 3,6)	-	W		
		SO Package14	-	1.02 (Note 4,6)	-	1.02 (Note 4,6)			
		Mini SO8	-	0.84 (Note 5,6)	-	0.84 (Note 5,6)			
Differential Input Voltage (Note 7)		V _{ID}	36						
Input Common-mode Voltage Range		V _{ICM}	(Vcc ⁻ -0.3) to (Vcc ⁻ +36)						
Input Current (Note 8)		I_1	-10						
Operating Supply Voltage	Vopr		+3.0 to +36.0 (±1.5 to ±18.0)						
Operating Temperature Range	T _{OPR}								
Storage Temperature Range	T _{STG}		-55 to +150						
Maximum Junction Temperature		T _{JMAX}	+150						

Note: Absolute maximum rating item indicates the condition which must not be exceeded. Application if voltage in excess of absolute maximum rating or use out of absolute maximum rated temperature environment may cause deterioration of characteristics.

(Note 1) To use at temperature above T_A=25°C reduce 5.4mW.

(Note 2) To use at temperature above T_A=25°C reduce 5.0mW

(Note 3) To use at temperature above T_A=25°C reduce 4.7mW.

(Note 4) To use at temperature above $T_A=25^{\circ}C$ reduce 8.2mW.

(Note 5) To use at temperature above T_A =25°C reduce 6.8mW

(Note 6) Mounted on a FR4 glass epoxy PCB 70mm×70mm×1.6mm(Copper foil area less than 3%).

(Note 7) The voltage difference between inverting input and non-inverting input is the differential input voltage.

Then input terminal voltage is set to more than Vcc.

(Note 8) An excessive input current will flow when input voltages of less than Vcc-0.6V are applied.

The input current can be set to less than the rated current by adding a limiting resistor.

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Electrical Characteristics

OLM358xxx (Unless otherwise specified, Vcc⁺=+5V, Vcc⁻=0V)

Parameter	Symbol	Temperature Range	Min.	Limit Typ.	Max.	Unit	Conditions	
(Alata 0)		25°C	_	2	7		VO=1.4V,RS=0Ω	
Input Offset Voltage (Note 9)	V_{IO}	Full Range	_	_	9	mV	5V< Vcc ⁺ <30V 0 <vic< vcc<sup="">+-1.5V</vic<>	
(Note 9)		25°C	_	2	30	_		
Input Offset Current (Note 9)	I _{IO}	Full Range	_	_	100	nA	VO=1.4V	
Input Bias Current (Note 9)	I _B	25°C	_	20	150	nA	VO=1.4V	
input bias Current	ıB	Full Range	_	_	200	шА		
Large Signal Voltage Gain	A _V	25°C	25	100	_	V/mV	$Vcc^{+}=15V$ VO=1.4V to 11.4V $RL=2k\Omega$	
Supply Voltage Rejection Ratio	PSRR	25°C	65	100	_	dB	RS≦10kΩ	
Supply Voltage Rejection Ratio	FORK	Full Range	65	_	_	uБ	Vcc ⁺ =5V to 30V	
Supply Current	Icc	Full Range	_	0.7	1.2	mA	Vcc ⁺ =5V,No Load	
Зарріу Сапені	icc	i uli ixange	_	_	2	ША	Vcc ⁺ =30V,No Load	
Input Common-mode Voltage	V _{ICM}	25°C	0	_	Vcc ⁺ -1.5	V	Vcc ⁺ =30V	
Range	V ICIVI	Full Range	0	_	Vcc ⁺ -2.0	v	RS≦10kΩ	
Common-mode Rejection Ratio	CMRR	25°C	70	85	_	dB	RS≦10kΩ	
Common mode Rejection Ratio	OWNER	Full Range	60	_	_	uВ		
Output Source Current (Note 10)	I _{SOURCE}	25°C	20	40	60	mA	Vcc ⁺ =15V,VO=+2V VID=+1V	
(Noto 10)			10	20	_	mA	VO=+2V, Vcc ⁺ =15V ,VID=-1V	
Output Sink Current (Note 10)	I _{SINK}	25°C	12	50	_	μA	VO=+0.2V, Vcc ⁺ =15V ,VID=-1V	
Outrot Valtana Outra	\/	25°C	_	_	Vcc ⁺ -1.5	V	RL=2kΩ	
Output Voltage Swing	Vopp	Full Range	_	_	Vcc ⁺ -2.0	V		
High Lavel Output Valtage		25°C	27	28	_		\/aa ⁺ 20\/ DL 40\/ O	
High Level Output Voltage	V _{OH}	Full Range	27	_	_	V	$Vcc^{+}=30V,RL=10k\Omega$	
Lavel aval Ovitovit Valtage		25°C	_	5	20	\/	DI 40kO	
Low Level Output Voltage	V _{OL}	Full Range	_	_	20	mV	RL=10kΩ	
Slew Rate	SR	25°C	_	0.3	_	V/µs	RL=2kΩ,CL=100pF, Vcc ⁺ =15V VI=0.5V to 3V, Unity Gain	
Gain Bandwidth Product	GBP	25°C	_	0.6	-	MHz	Vcc ⁺ =30V,RL=2kΩ, CL=100pF VIN=10mV,f=100kHz	
Total Harmonic Distortion	THD	25°C	_	0.02	_	%	f=1kHz,AV=20dB RL=2kΩ CL=100pF,VO=2Vpp	
Input Equivalent Noise Voltage	V _N	25°C	_	40	_	nV/√Hz	$f=1kHz,RS=100\Omega$ $Vcc^{+}=30V$	
Input Offset Voltage Drift (Note 9)	ΔV _{IO} /ΔΤ	_	_	7	_	μV/°C	_	
Input Offset Current Drift (Note 9)	ΔΙ _{ΙΟ} /ΔΤ	_	_	10	_	pA/°C	_	
Channel Separation	cs	25°C	_	120	_	dB	1kHz≦f≦20kHz	

⁽Note 9) Absolute value

⁽Note 10) Under high temperatures, please consider the power dissipation when selecting the output current.

When output terminal is continuously shorted the output current reduces the internal temperature by flushing.

Electrical Characteristics - continued

OLM324xxx (Unless otherwise specified, Vcc⁺=+5V, Vcc⁻=0V)

C =c= (C outlot wide oper	, u, voo	,	,			1		
Parameter	Symbol	Temperature Range	Min.	Limit	Max.	Unit	Conditions	
		_	IVIII I.	Тур.			VO 1 4V/BC 00	
Input Offset Voltage (Note 11)	V _{IO}	25°C Full Range		_	9	mV	VO=1.4V,RS=0Ω 5V< Vcc ⁺ <30V 0 <vic< vcc<sup="">+-1.5V</vic<>	
(Note 44)		25°C	_	2	30			
Input Offset Current (Note 11)	I _{IO}	Full Range	_	_	100	nA	VO=1.4V	
(Note 11)		25°C	_	20	150			
Input Bias Current (Note 11)	I _B	Full Range	_	_	300	nA	VO=1.4V	
Large Signal Voltage Gain	Av	25°C	25	100	_	V/mV	Vcc ⁺ =15V VO=1.4V to 11.4V RL=2kΩ	
Supply Voltage Bajection Batio	PSRR	25°C	65	110	_	dB	RS≦10kΩ	
Supply Voltage Rejection Ratio	FORK	Full Range	65	_	_	uБ	Vcc ⁺ =5V to 30V	
		25°C	_	0.7	1.2		Vcc ⁺ =5V,No Load	
Supply Company		25°C	-	1.5	3	A	Vcc ⁺ =30V,No Load	
Supply Current	I _{CC}	Full Range	_	0.8	1.2	mA	Vcc ⁺ =5V,No Load	
		Full Range	-	1.5	3		Vcc ⁺ =30V,No Load	
Input Common-mode Voltage	.,	25°C	0	_	Vcc ⁺ -1.5	.,	\(\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	
Range	V _{ICM}	Full Range	0	_	Vcc ⁺ -2.0	· V	Vcc ⁺ =30V	
Common made Deigntion Detic	CMDD	25°C	70	80	_	40	DC < 10k0	
Common-mode Rejection Ratio	CMRR	Full Range	60	_	_	dB	RS≦10kΩ	
Output Source Current (Note 12)	I _{SOURCE}	25°C	20	40	70	mA	Vcc ⁺ =15V,VO=+2V VID=+1V	
Output Sink Current (Note 12)	1	25°C	10	20	_	mA	VO=+2V, Vcc ⁺ =15V,VID=-1V	
Output Sink Gunent	Isink	25 C	12	50	_	μΑ	VO=+0.2V, Vcc ⁺ =15V ,VID=-1V	
Output Voltage Swing	Vopp	25°C	_	_	Vcc ⁺ -1.5	V	RL=2kΩ	
Catput voltage Cwing	ТОРР	Full Range	-	_	Vcc ⁺ -2.0	•	IVE-ZNS2	
High Level Output Voltage	V _{OH}	25°C	27	28	_	V	Vcc ⁺ =30V,RL=10kΩ	
Tilgit Lovor Gatpat Voltage	*011	Full Range	27	_	_	•	V00 =00 V,1 (2= 10 (22	
Low Level Output Voltage	V _{OL}	25°C	_	5	20	mV	RL=10kΩ	
		Full Range	_	_	20			
Slew Rate	SR	25°C	-	0.3	_	V/µs	RL=2kΩ,CL=100pF, Vcc ⁺ =15V VI=0.5V to 3V, Unity Gain	
Gain Bandwidth Product	GBP	25°C	_	0.6	_	MHz	Vcc ⁺ =30V,RL=2kΩ, CL=100pF VIN=10mV,f=100kHz	
Total Harmonic Distortion	THD	25°C	_	0.015	_	%	f=1kHz,AV=20dB RL=2kΩ CL=100pF,VO=2Vpp	
Input Equivalent Noise Voltage	V _N	25°C		40	_	nV/√Hz	f=1kHz,RS=100Ω Vcc ⁺ =30V	
Input Offset Voltage Drift (Note 11)	ΔV _{IO} /ΔΤ	_	_	7	_	μV/°C	_	
Input Offset Current Drift (Note 11)	ΔΙ _{ΙΟ} /ΔΤ	_	-	10	_	pA/°C	_	
Channel Separation	CS	25°C	_	120	_	dB	1kHz≦f≦20kHz	

(Note 11) Absolute value

⁽Note 12) Under high temperatures, please consider the power dissipation when selecting the output current.

When output terminal is continuously shorted the output current reduces the internal temperature by flushing.

Electrical Characteristics - continued

OLM2904xxx (Unless otherwise specified, Vcc⁺=+5V, Vcc⁻=0V)

Deremeter		Temperature	Limit			Lloit	Conditions	
Parameter	Symbol	Range	Min.	Тур.	Max.	Unit	Conditions	
Input Offset Voltage (Note 13)	V _{IO}	25°C	_	2	7	mV	VO=1.4V	
mpat Onset Voltage	V 10	Full Range	ı	_	9	1110	VO=1.4V	
Input Offset Current (Note 13)	I _{IO}	25°C	_	2	50	nA	VO=1.4V	
mpat enect earrein	10	Full Range	_	_	200	.,,		
Input Bias Current (Note 13)	I _B	25°C	_	20	150	nA	VO=1.4V	
		Full Range	_	_	200			
Large Signal Voltage Gain	A _V	25°C	25	100	_	V/mV	Vcc ⁺ =15V VO=1.4V to 11.4V RL=2kΩ	
Supply Voltage Rejection Ratio	PSRR	25°C	65	100	_	dB	RS≦10kΩ	
Supply voltage Rejection Ratio	TOKK	Full Range	65	_	_	QD.	Vcc ⁺ =5V to 30V	
Supply Current	Icc	25°C	_	0.7	1.2	mA	Vcc ⁺ =5V,No Load	
опры оптен	icc	Full Range	-	_	2	111/5	VCC =5 V,1 VO E0 au	
Input Common-mode Voltage	V _{ICM}	25°C	0	_	Vcc ⁺ -1.5	V	Vcc ⁺ =30V	
Range	VICIVI	Full Range	0	_	Vcc ⁺ -2.0	•	V 30 -30 V	
Common-mode Rejection Ratio	CMRR	25°C	70	85	_	dB	RS=10kΩ	
	J	Full Range	60	_	_			
Output Source Current (Note 14)	I _{SOURCE}	25°C	20	40	60	mA	Vcc ⁺ =+15V,VO=+2V VID=+1V	
Output Sink Current (Note 14)	Januar .	25°C	10	20	_	mA	VO=2V,Vcc ⁺ =+5V VID=-1V	
Output Sink Current	Isink	25 0	12	50	_	μA	VO=+0.2V, Vcc ⁺ =+15V ,VID=-1V	
Output Voltage Swing	Vopp	25°C	1	_	Vcc ⁺ -1.5	V	RL=2kΩ	
Carpat Voltago Civing	ТОРР	Full Range	_	_	Vcc ⁺ -2.0	•	112-2132	
High Level Output Voltage	V _{OH}	25°C	27	_	_	V	Vcc ⁺ =30V,RL=10kΩ	
	- 011	Full Range	27	28	_	-		
Low Level Output Voltage	V _{OL}	25°C	_	5	20	mV	RL=10kΩ	
	02	Full Range	_	_	20			
Slew Rate	SR	25°C	_	0.3	_	V/µs	RL=2kΩ,CL=100pF, Unity Gain VI=0.5V to 3V Vcc ⁺ =15V	
Gain Bandwidth Product	GBP	25°C	ı	0.6	_	MHz	Vcc ⁺ =30V,RL=2kΩ CL=100pF VIN=10mV	
Total Harmonic Distortion	THD	25°C	_	0.02	_	%	$\begin{array}{l} \text{f=1kHz,AV=20dB} \\ \text{RL=2k}\Omega \\ \text{CL=100pF,} \\ \text{Vcc}^+ = 30\text{V,VO=2Vpp} \end{array}$	
Input Equivalent Noise Voltage	V _N	25°C	_	40	_	nV/√Hz	f=1kHz,RS=100Ω Vcc ⁺ =30V	
Input Offset Voltage Drift (Note 13)	$\Delta V_{IO}/\Delta T$	_	_	7	_	μV/°C	-	
Input Offset Current Drift (Note 13)	ΔΙ _{ΙΟ} /ΔΤ	_	_	10	_	pA/°C	-	
Channel Separation	CS	25°C	_	120	_	dB	1kHz≦f≦20kHz	

⁽Note 13) Absolute value

⁽Note 14) Under high temperatures, please consider the power dissipation when selecting the output current.

When the output terminal is continuously shorted the output current reduces the internal temperature by flushing.

Electrical Characteristics - continued

OLM2902xxx (Unless otherwise specified, Vcc⁺=+5V, Vcc⁻=0V)

Parameter	Symbol	Temperature Range	Min.	Limit Typ.	Max.	Unit	Conditions	
(Note 15)		25°C	_	2	7			
Input Offset Voltage (Note 15)	V _{IO}	Full Range	_	_	9	mV	VO=1.4V	
Input Offset Current (Note 15)	I _{IO}	25°C	_	2	30	nA	VO=1.4V	
	-10	Full Range	_	_	200			
Input Bias Current (Note 15)	I _B	25°C	_	20	150	nA	VO=1.4V	
•		Full Range	_	_	300		\\ ⁺ 45\\	
Large Signal Voltage Gain	Av	25°C	25	100	_	V/mV	$Vcc^{+}=15V$ VO=1.4V to 11.4V $RL=2k\Omega$	
Supply Voltage Rejection Ratio	PSRR	25°C	65	110	_	dB	RS≦10kΩ	
Supply voltage rejection realio	1 OKK	Full Range	65	_	_	ub.	Vcc ⁺ =5V to 30V	
		25°C	_	0.7	1.2		Vcc ⁺ =5V,No Load	
Cumply Current		25°C	_	1.5	3	A	Vcc ⁺ =30V,No Load	
Supply Current	Icc	Full Range	_	0.8	1.2	mA	Vcc ⁺ =5V,No Load	
		Full Range	_	1.5	3		Vcc ⁺ =30V,No Load	
Input Common-mode Voltage	\/	25°C	0	_	Vcc ⁺ -1.5	V	Vcc ⁺ =30V	
Range	V _{ICM}	Full Range	0	_	Vcc ⁺ -2.0	V	V 30 -00 V	
Common-mode Rejection Ratio	CMRR	25°C	70	80	_	dB	RS=10kΩ	
Common-mode Rejection Ratio	CIVINN	Full Range	60	_	_	uБ		
Output Source Current (Note 16)	I _{SOURCE}	25°C	20	40	70	mA	Vcc ⁺ =+15V,VO=+2V VID=+1V	
(Note 16)			10	20	_	mA	VO=2V,Vcc ⁺ =+5V VID=-1V	
Output Sink Current (Note 16)	Isink	25°C	12	50	_	μA	VO=+0.2V, Vcc ⁺ =+15V ,VID=-1\	
0	.,	25°C	_	_	Vcc ⁺ -1.5			
Output Voltage Swing	Vopp	Full Range	_	_	Vcc ⁺ -2.0	V		
High Lovel Output Voltage	\/	25°C	27	28	_	V	Voot 20V DL 40kO	
High Level Output Voltage	V _{OH}	Full Range	27	_	_	V	$Vcc^{+}=30V,RL=10k\Omega$	
Low Level Output Voltage	V _{OL}	25°C	_	5	20	mV	RL=10kΩ	
Low Level Output voltage	VOL	Full Range	_	_	20	IIIV	-	
Slew Rate	SR	25°C	_	0.3	_	V/µs	RL= $2k\Omega$,CL= $100pF$, Unity Gain VI= $0.5V$ to $3V$ $Vcc^{+}=15V$	
Gain Bandwidth Product	GBP	25°C	_	0.3	_	MHz	Vcc ⁺ =30V,RL=2kΩ CL=100pF VIN=10mV	
Total Harmonic Distortion	THD	25°C	_	0.015	_	%	f=1kHz,AV=20dB RL=2kΩ CL=100pF, Vcc ⁺ =30V,VO=2Vpp	
Input Equivalent Noise Voltage	V _N	25°C	_	40	_	nV/√Hz	f=1kHz,RS=100Ω Vcc ⁺ =30V	
Input Offset Voltage Drift (Note 15)	ΔV _{IO} /ΔΤ	_	_	7	_	μV/°C	-	
Input Offset Current Drift (Note 15)	ΔΙ _{ΙΟ} /ΔΤ	_	_	10	_	pA/°C	-	
Channel Separation	CS	25°C	_	120	_	dB	1kHz≦f≦20kHz	

(Note 15) Absolute value

(Note 16) Under high temperatures, please consider the power dissipation when selecting the output current.

When the output terminal is continuously shorted the output current reduces the internal temperature by flushing.

Description of Electrical Characteristics

Described below are descriptions of the relevant electrical terms used in this datasheet. Items and symbols used are also shown. Note that item name and symbol and their meaning may differ from those on another manufacturer's document or general document.

1. Absolute maximum ratings

Absolute maximum rating items indicate the condition which must not be exceeded. Application of voltage in excess of absolute maximum rating or use out of absolute maximum rated temperature environment may cause deterioration of characteristics.

(1) Supply Voltage (Vcc⁺/ Vcc⁻)

Indicates the maximum voltage that can be applied between the positive power supply terminal and negative power supply terminal without deterioration or destruction of characteristics of internal circuit.

(2) Differential Input Voltage (V_{ID})

Indicates the maximum voltage that can be applied between non-inverting and inverting terminals without damaging the IC.

(3) Input Common-mode Voltage Range (V_{ICM})

Indicates the maximum voltage that can be applied to the non-inverting and inverting terminals without deterioration or destruction of electrical characteristics. Input common-mode voltage range of the maximum ratings does not assure normal operation of IC. For normal operation, use the IC within the input common-mode voltage range characteristics.

(4) Operating and storage temperature ranges (Topr, Tstg)

The operating temperature range indicates the temperature range within which the IC can operate. The higher the ambient temperature, the lower the power consumption of the IC. The storage temperature range denotes the range of temperatures the IC can be stored under without causing excessive deterioration of the electrical characteristics.

(5) Power dissipation (PD)

Indicates the power that can be consumed by the IC when mounted on a specific board at the ambient temperature 25°C (normal temperature). As for package product, Pd is determined by the temperature that can be permitted by the IC in the package (maximum junction temperature) and the thermal resistance of the package.

2. Electrical characteristics

(1) Input Offset Voltage (V_{IO})

Indicates the voltage difference between non-inverting terminal and inverting terminals. It can be translated into the input voltage difference required for setting the output voltage at 0 V.

(2) Input Offset Voltage drift $(\Delta V_{IO}/\Delta T)$

Denotes the ratio of the input offset voltage fluctuation to the ambient temperature fluctuation.

(3) Input Offset Current (I_{IO})

Indicates the difference of input bias current between the non-inverting and inverting terminals.

(4) Input Offset Current Drift (△Iio/△T)

Signifies the ratio of the input offset current fluctuation to the ambient temperature fluctuation.

(5) Input Bias Current (I_B)

Indicates the current that flows into or out of the input terminal. It is defined by the average of input bias currents at the non-inverting and inverting terminals.

(6) Supply Current (ICC)

Indicates the current that flows within the IC under specified no-load conditions.

(7) Maximum Output Voltage(High) / Maximum Output Voltage(Low) (VOH/VOL)

Indicates the voltage range of the output under specified load condition. It is typically divided into maximum output voltage High and low. Maximum output voltage high indicates the upper limit of output voltage. Maximum output voltage low indicates the lower limit.

(8) Large Signal Voltage Gain (Av)

Indicates the amplifying rate (gain) of output voltage against the voltage difference between non-inverting terminal and inverting terminal. It is normally the amplifying rate (gain) with reference to DC voltage.

Av = (Output voltage) / (Differential Input voltage)

(9) Input Common-mode Voltage Range (V_{ICM})

Indicates the input voltage range where IC normally operates.

(10) Common-mode Rejection Ratio (CMRR)

Indicates the ratio of fluctuation of input offset voltage when the input common mode voltage is changed. It is normally the fluctuation of DC.

CMRR = (Change of Input common-mode voltage)/(Input offset fluctuation)

(11) Power Supply Rejection Ratio (PSRR)

Indicates the ratio of fluctuation of input offset voltage when supply voltage is changed.

It is normally the fluctuation of DC.

PSRR= (Change of power supply voltage)/(Input offset fluctuation)

(12) Output Source Current/ Output Sink Current (I_{source} / I_{sink})

The maximum current that can be output from the IC under specific output conditions. The output source current indicates the current flowing out from the IC, and the output sink current indicates the current flowing into the IC. indicates the current flowing out from the IC, and the output sink current indicates the current flowing into the IC.

(13) Channel Separation (CS)

Indicates the fluctuation in the output voltage of the driven channel with reference to the change of output voltage of the channel which is not driven.

(14) Slew Rate (SR)

Indicates the ratio of the change in output voltage with time when a step input signal is applied.

(15) Gain Bandwidth (GBW)

The product of the open-loop voltage gain and the frequency at which the voltage gain decreases 6dB/octave.

(16) Input Referred Noise Voltage (V_N)

Indicates a noise voltage generated inside the operational amplifier equivalent by ideal voltage source connected in series with input terminal.

Typical Performance Curves

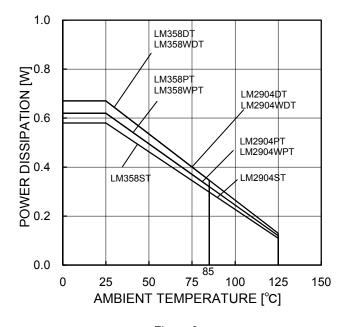


Figure 2. Derating Curve

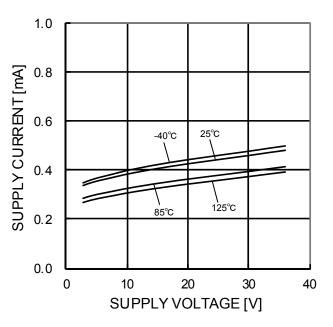


Figure 3.
Supply Current- Supply Voltage

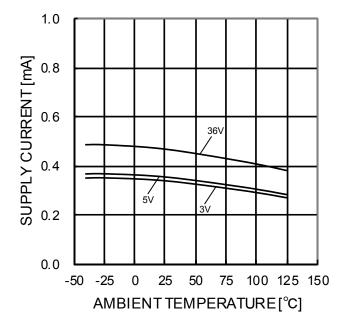
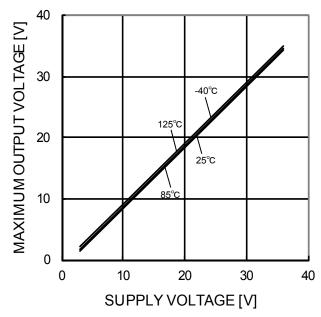


Figure 4.
Supply Current – Ambient Temperature



 $\label{eq:Figure 5.} Figure 5. \\ Maximum Output Voltage - Supply Voltage \\ (RL=10k\Omega)$

^(*) The above data is measurement value of typical sample, it is not guaranteed. LM358 : -40°C to +85°C LM2904 : -40°C to +125°C

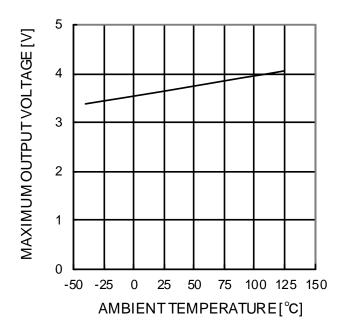


Figure 6.

Maximum Output Voltage - Ambient Temperature (Vcc⁺=5V, RL=2kΩ)

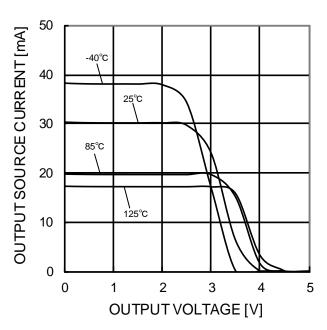


Figure 7.
Output Source Current - Output Voltage (Vcc⁺=5V)

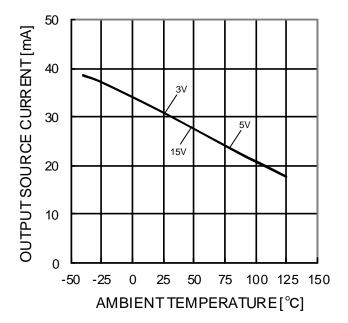


Figure 8.
Output Source Current - Ambient Temperature
(OUT=0V)

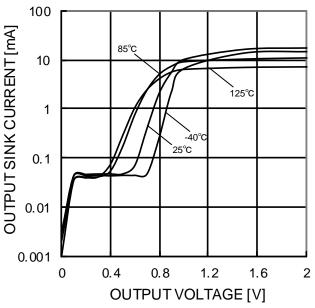


Figure 9.
Output Sink Current - Output Voltage (Vcc⁺=5V)

^(*) The above data is measurement value of typical sample, it is not guaranteed. LM358 : -40°C to +70°C LM2904 : -40°C to +125°C

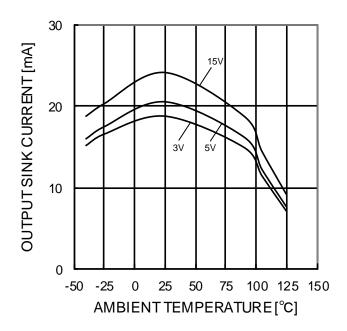


Figure 10.
Output Sink Current - Ambient Temperature
(OUT= Vcc⁺)

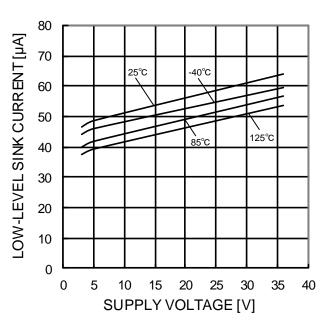


Figure 11.
Low Level Sink Current - Supply Voltage (OUT=0.2V)

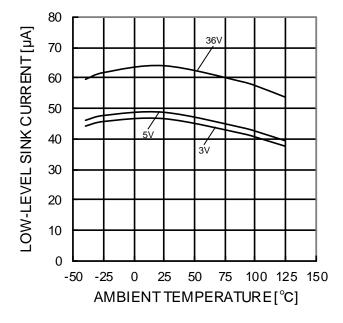


Figure 12. Low Level Sink Current - Ambient Temperature (OUT=0.2V)

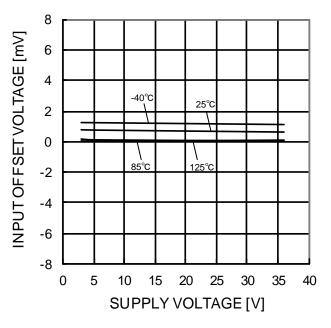


Figure 13.
Input Offset Voltage - Supply Voltage (V_{ICM}=0V, OUT=1.4V)

^(*) The above data is measurement value of typical sample, it is not guaranteed. LM358 : -40°C to +85°C LM2904 : -40°C to +125°C

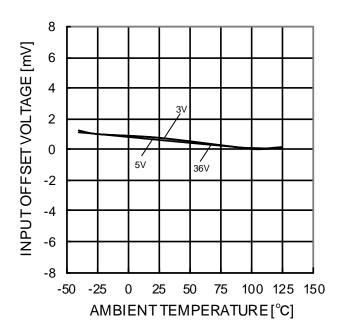


Figure 14. Input Offset Voltage - Ambient Temperature $(V_{ICM}=0V,\ OUT=1.4V)$

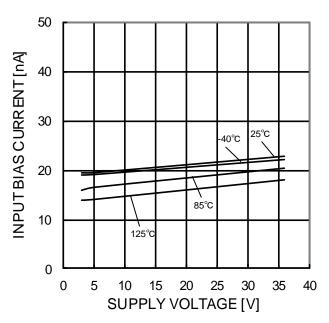


Figure 15.
Input Bias Current - Supply Voltage
(V_{ICM}=0V, OUT=1.4V)

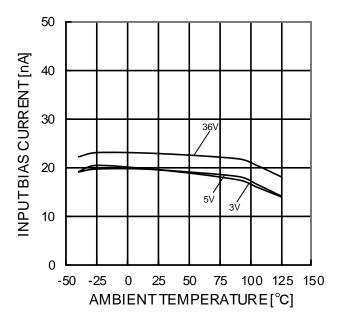


Figure 16.
Input Bias Current - Ambient Temperature
(V_{ICM}=0V, OUT=1.4V)

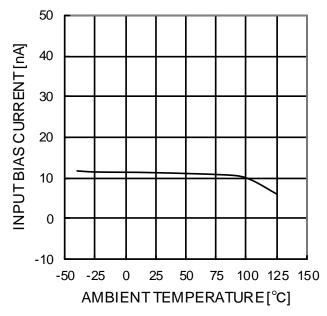


Figure 17.
Input Bias Current - Ambient Temperature (Vcc⁺=30V, V_{ICM}=28V, OUT=1.4V)

^(*) The above data is measurement value of typical sample, it is not guaranteed. LM358 : -40°C to +85°C LM2904 : -40°C to +125°C

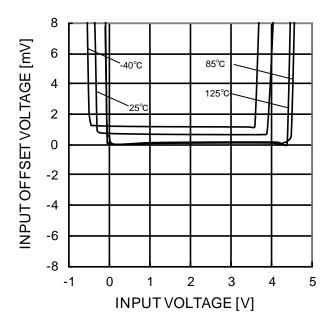


Figure 18.
Input Offset Voltage - Common Mode Input Voltage (Vcc⁺=5V)

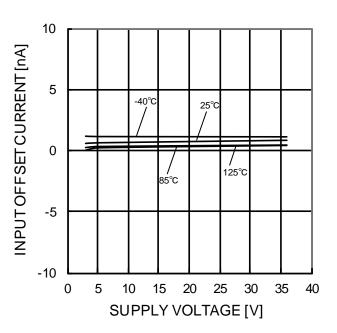


Figure 19.
Input Offset Current - Supply Voltage
(V_{ICM}=0V, OUT=1.4V)

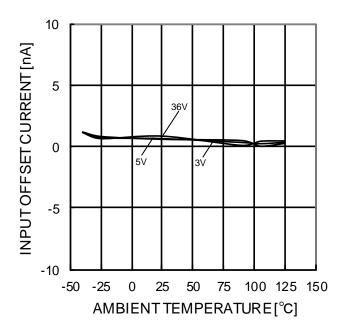


Figure 20. Input Offset Current - Ambient Temperature $(V_{ICM}=0V, OUT=1.4V)$

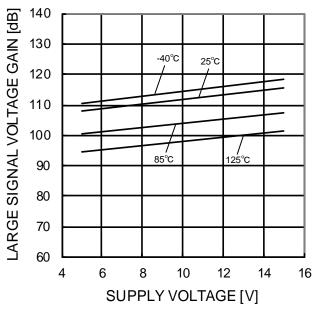


Figure 21.

Large Signal Voltage Gain - Supply Voltage $(RL=2k\Omega)$

^(*) The above data is measurement value of typical sample, it is not guaranteed. LM358 : -40°C to +85°C LM2904 : -40°C to +125°C

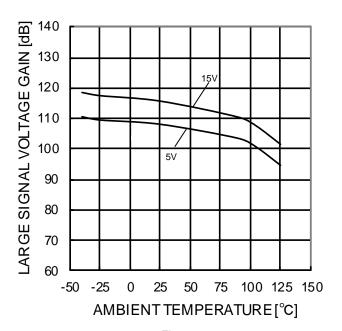


Figure 22. Large Signal Voltage Gain - Ambient Temperature (RL=2kΩ)

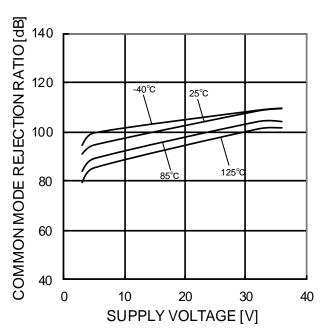


Figure 23.
Common Mode Rejection Ratio
- Supply Voltage

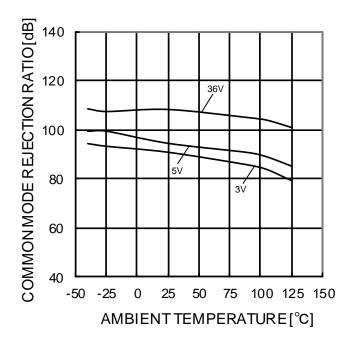


Figure 24.
Common Mode Rejection Ratio
- Ambient Temperature

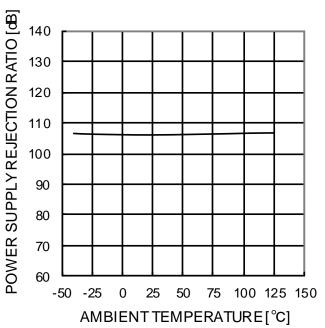
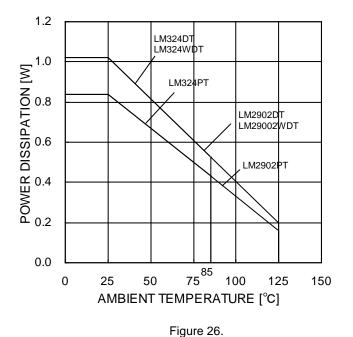


Figure 25.
Power Supply Rejection Ratio
- Ambient Temperature

^(*) The above data is measurement value of typical sample, it is not guaranteed. LM358 : -40°C to +85°C LM2904 : -40°C to +125°C

OLM324xxx, LM2902xxx



Derating Curve

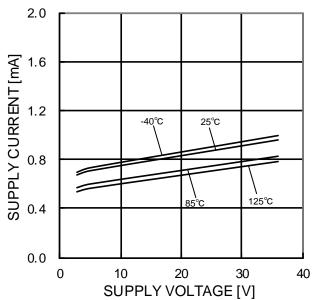
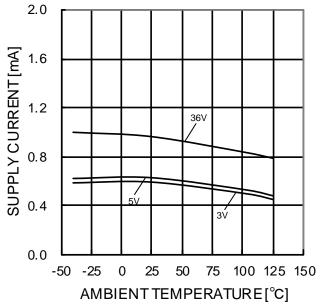
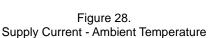


Figure 27. Supply Current - Supply Voltage





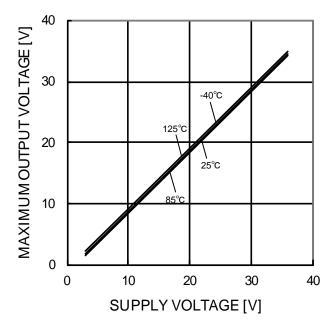


Figure 29.

Maximum Output Voltage - Supply Voltage (RL=10kΩ)

^(*) The above data is measurement value of typical sample, it is not guaranteed. LM324 : -40°C to +85°C LM2902 : -40°C to +125°C

O LM324xxx, LM2902xxx

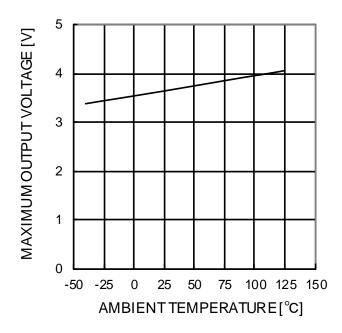


Figure 30.

Maximum Output Voltage - Ambient Temperature (Vcc⁺=5V, RL=2kΩ)

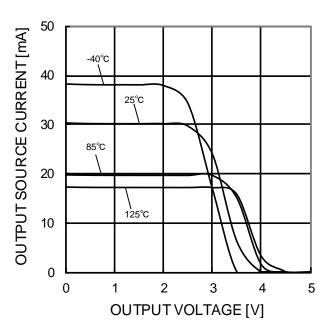


Figure 31.
Output Source Current - Output Voltage
(Vcc⁺=5V)

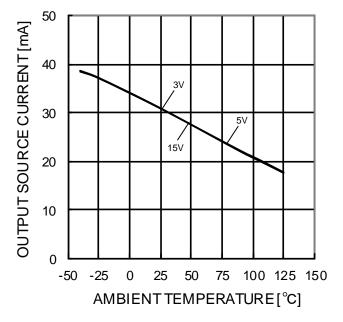


Figure 32.
Output Source Current - Ambient Temperature (OUT=0V)

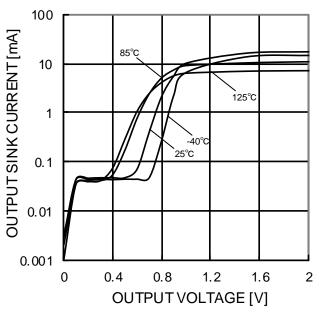


Figure 33.
Output Sink Current - Output Voltage (Vcc⁺=5V)

^(*) The above data is measurement value of typical sample, it is not guaranteed. LM324 : -40°C to +85°C LM2902 : -40°C to +125°C

O LM324xxx, LM2902xxx

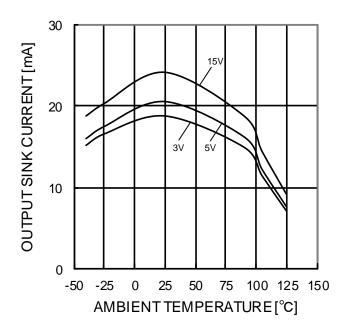


Figure 34.
Output Sink Current - Ambient Temperature
(OUT= Vcc⁺)

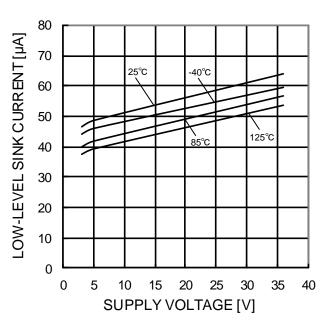


Figure 35.
Low Level Sink Current - Supply Voltage (OUT=0.2V)

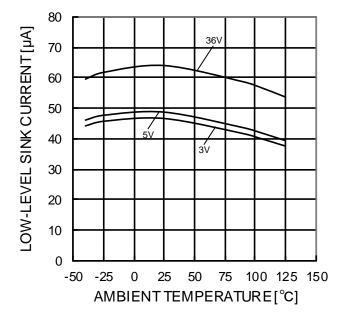


Figure 36.
Low Level Sink Current - Ambient Temperature (OUT=0.2V)

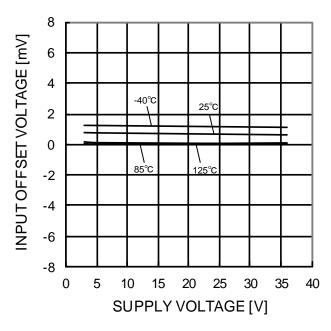


Figure 37.
Input Offset Voltage - Supply Voltage (V_{ICM}=0V, OUT=1.4V)

^(*) The above data is measurement value of typical sample, it is not guaranteed. LM324 : -40°C to +85°C LM2902 : -40°C to +125°C

OLM324xxx, LM2902xxx

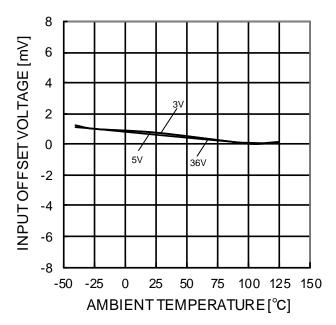


Figure 38.
Input Offset Voltage - Ambient Temperature (V_{ICM}=0V, OUT=1.4V)

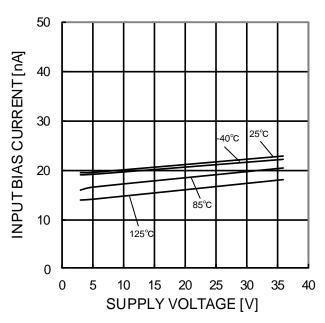


Figure 39.
Input Bias Current - Supply Voltage
(V_{ICM}=0V, OUT=1.4V)

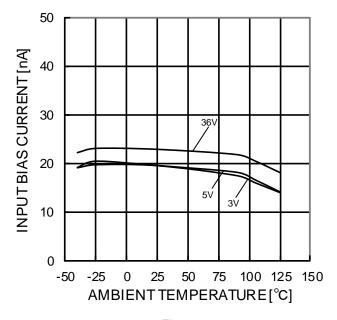


Figure 40.
Input Bias Current - Ambient Temperature
(V_{ICM}=0V, OUT=1.4V)

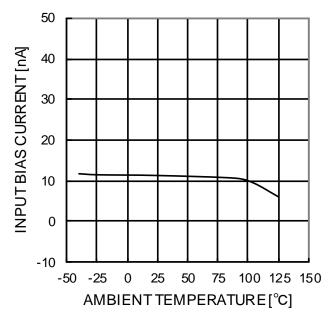


Figure 41.
Input Bias Current - Ambient Temperature (Vcc⁺=30V, V_{ICM}=28V, OUT=1.4V)

^(*) The above data is measurement value of typical sample, it is not guaranteed. LM324 : -40°C to +85°C LM2902 : -40°C to +125°C

OLM324xxx, LM2902xxx

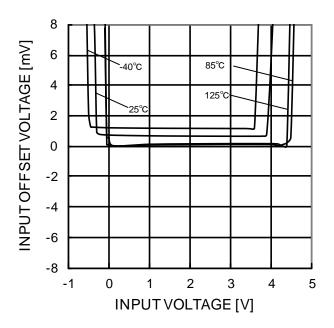


Figure 42.
Input Offset Voltage - Common Mode Input Voltage (Vcc⁺=5V)

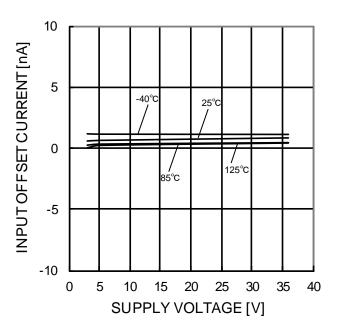


Figure 43.
Input Offset Current - Supply Voltage
(V_{ICM}=0V, OUT=1.4V)

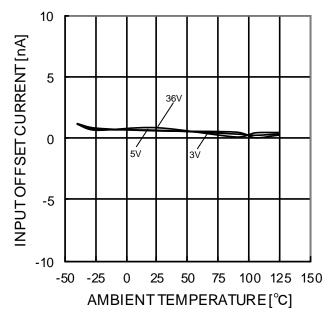


Figure 44. Input Offset Current - Ambient Temperature $(V_{ICM}=0V, OUT=1.4V)$

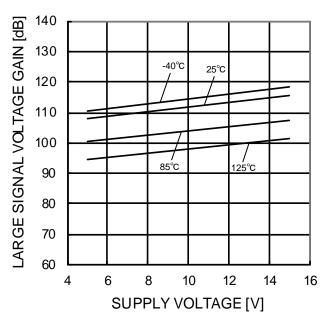


Figure 45. Large Signal Voltage Gain - Supply Voltage $(RL=2k\Omega)$

^(*) The above data is measurement value of typical sample, it is not guaranteed. LM324 : -40°C to +85°C LM2902 : -40°C to +125°C

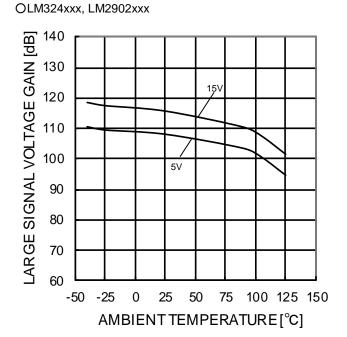


Figure 46.
Large Signal Voltage Gain - Ambient Temperature (RL= $2k\Omega$)

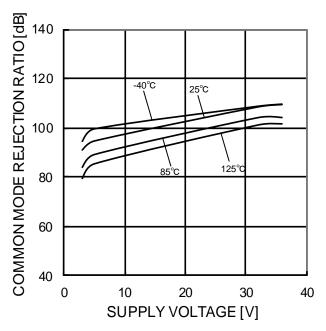


Figure 47.
Common Mode Rejection Ratio
- Supply Voltage

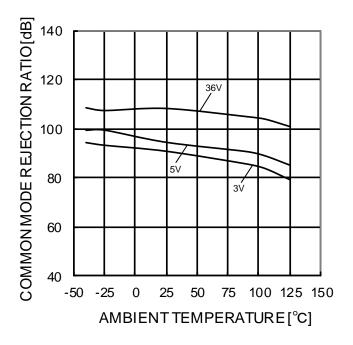


Figure 48.
Common Mode Rejection Ratio
- Ambient Temperature

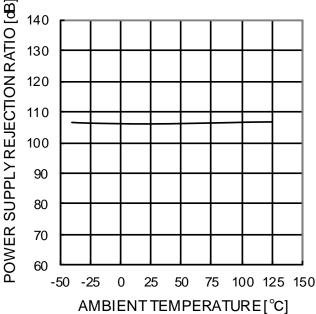


Figure 49.
Power Supply Rejection Ratio
- Ambient Temperature

^(*) The above data is measurement value of typical sample, it is not guaranteed. LM324 : -40°C to +85°C LM2902 : -40°C to +125°C

Application Information

Measurement Circuit 1 NULL Method Measurement Condition

Parameter	VF	S1	S2	S3	Vcc ⁺	Vcc ⁻	EK	Vicm	Calculation	
Input Offset Voltage	VF1	ON	ON	OFF	5 to 30	0	-1.4	0	1	
Input Offset Current	VF2	OFF	OFF	OFF	5	0	-1.4	0	2	
Input Pigg Current	VF3	OFF	ON	OFF	5	0	-1.4	0	3	
Input Bias Current	VF4	ON	OFF	OFF	5	0	-1.4	0	3	
Lorgo Signal Voltago Cain	VF5	ON	ON	ON	15	0	-1.4	0	4	
Large Signal Voltage Gain	VF6	ON			15	0	-11.4	0	4	
Common mode Painstian Patio	VF7	ON	ON	OFF	5	0	-1.4	0	5	
Common-mode Rejection Ratio	VF8	ON	ON	OFF	5	0	-1.4	3.5	5	
Supply Voltage Rejection Ratio	VF9	VF9		OFF	5	0	-1.4	0	6	
Supply Voltage Rejection Ratio	VF10	ON	ON	OFF	30	0	-1.4	0	6	

-Calculation-

1. Input Offset Voltage (Vio)

$$V_{IO} = \frac{|V_{F1}|}{1 + R_F/R_S} \ [V]$$

2. Input Offset Current (lio)

$$I_{IO} = \frac{|V_{F2}-V_{F1}|}{R_1 \times (1+R_F/R_S)}$$
 [A]

3. Input Bias Current (lb)

$$I_B = \frac{|V_{F4}-V_{F3}|}{2 \times R_1 \times (1+R_F/R_S)}$$
 [A]

4. Large Signal Voltage Gain (Av)

$$A_V = 20Log \frac{10 \times (1+R_F/R_S)}{|V_{F5}-V_{F6}|}$$
 [dB]

5. Common-mode Rejection Ration (CMRR)

$$\label{eq:cmr} \text{CMRR} \! = \! 20 \text{Log} \ \frac{3.5 \times (1 \! + \! R_{\text{F}} \! / \! R_{\text{S}})}{|V_{\text{F8}} \! - \! V_{\text{F7}}|} \ [\text{dB}]$$

6. Power supply rejection ratio (PSRR)

$$PSRR = 20Log \ \ \frac{25 \times (1 + R_F/R_S)}{|V_{F10} - V_{F9}|} \ \ [dB]$$

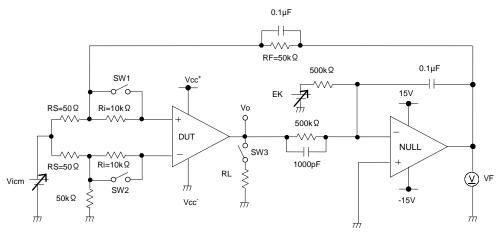


Figure . 50 Test circuit1 (one channel only)

Measurement Circuit2 Switch C	onditi	ion													
SW No.	SW 1	SW 2	SW 3	SW 4	SW 5	SW 6	SW 7	SW 8	SW 9	SW 10	SW 11	SW 12	SW 13	SW 14	SW 15
Supply Current	OFF	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	OFF	OFF
High level Output Voltage	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF
Low level Output Voltage	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF
Output source current	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	OFF	ON
Output sink current	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	OFF	ON
Slew Rate	OFF	OFF	OFF	ON	OFF	OFF	OFF	OFF	ON	ON	ON	OFF	OFF	OFF	OFF
Gain band width product	OFF	ON	OFF	OFF	OFF	ON	ON	OFF	OFF	ON	ON	OFF	OFF	OFF	OFF
Equivalent input noise voltage	ON	OFF	OFF	OFF	ON	OFF	ON	OFF	OFF	OFF	OFF	ON	OFF	OFF	OFF

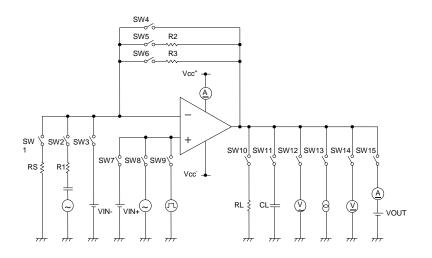


Figure 51 Measurement circuit2 (Each Op-Amps)

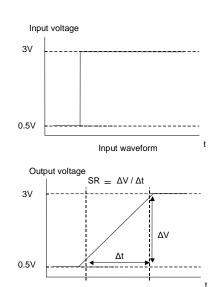


Figure 52 Slew Rate Input Waveform

Output waveform

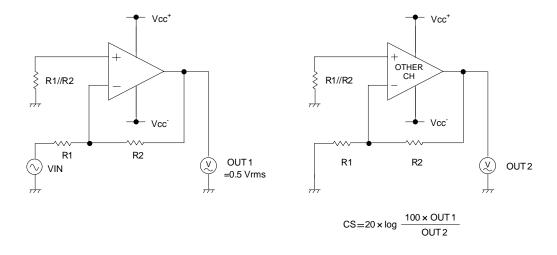
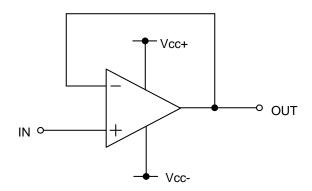


Figure 53 Measurement Circuit3 (Channel Separation) $(R1=1k\Omega, R2=100k\Omega)$

Examples of circuit

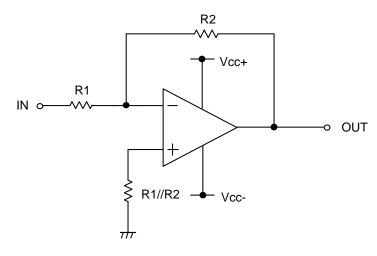
OVoltage follower



Voltage gain is 0 dB.

This circuit controls output voltage (OUT) equal input voltage (IN), and keeps OUT with stable because of high input impedance and low output impedance. OUT is shown next formula. OUT=IN

OInverting amplifier



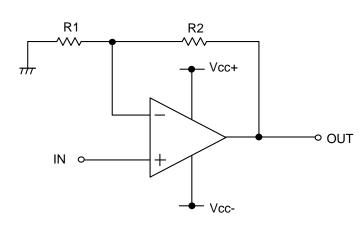
For inverting amplifier, IN is amplified by voltage gain decided R1 and R2, and phase reversed voltage is output.

OUT is shown next formula.

OUT=-(R2/R1) • IN

Input impedance is R1.

ONon-inverting amplifier



For non-inverting amplifier, IN is amplified by voltage gain decided R1 and R2, and phase is same with IN. OUT is shown next formula.

OUT= (1+R2/R1) • IN

This circuit realizes high input impedance because Input impedance is operational amplifier's input Impedance.

Power Dissipation

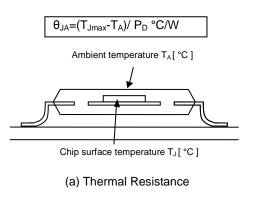
Power dissipation (total loss) indicates the power that the IC can consume at $T_A=25^{\circ}$ C (normal temperature). As the IC consumes power, it heats up, causing its temperature to be higher than the ambient temperature. The allowable temperature that the IC can accept is limited. This depends on the circuit configuration, manufacturing process, and consumable power.

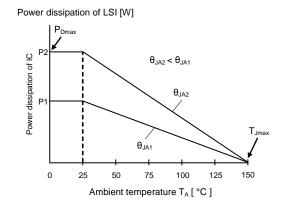
Power dissipation is determined by the allowable temperature within the IC (maximum junction temperature) and the thermal resistance of the package used (heat dissipation capability). Maximum junction temperature is typically equal to the maximum storage temperature. The heat generated through the consumption of power by the IC radiates from the mold resin or lead frame of the package. Thermal resistance, represented by the symbol θ_{JA} °C/W, indicates this heat dissipation capability. Similarly, the temperature of an IC inside its package can be estimated by thermal resistance.

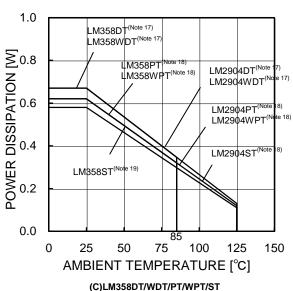
Figure 54(a) shows the model of the thermal resistance of a package. The equation below shows how to compute for the Thermal resistance (θ_{JA}), given the ambient temperature (T_A), maximum junction temperature (T_{Jmax}), and power dissipation (P_D).

$$\theta_{JA} = (T_{Jmax} - T_A) / P_D$$
 °C/W

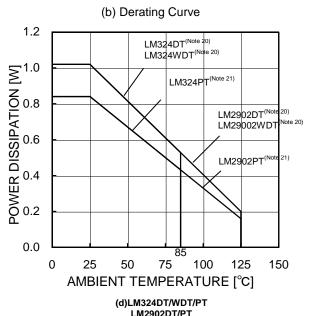
The derating curve in Figure 54(b) indicates the power that the IC can consume with reference to ambient temperature. Power consumption of the IC begins to attenuate at certain temperatures. This gradient is determined by Thermal resistance (θ_{JA}), which depends on the chip size, power consumption, package, ambient temperature, package condition, wind velocity, etc. This may also vary even when the same of package is used. Thermal reduction curve indicates a reference value measured at a specified condition. Figure 54(c), (d) shows an example of the derating curve for LM358xxx, LM2904xxx, LM324xxx and LM2902xxx.







LM2904DT/WDT/PT/WPT/ST



Power Dissipation

(Note 17)	(Note 18)	(Note 19)	(Note 20)	(Note 21)	Unit
6.2	5.4	5.0	8.2	7.0	mW/°C

Figure 54 Derating Curves

Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply terminals.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance ground and supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current GND traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the GND traces of external components do not cause variations on the GND voltage. The power supply and ground lines must be as short and thick as possible to reduce line impedance.

5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded, the rise in temperature of the chip may result in deterioration of the properties of the chip. The absolute maximum rating of the Pd stated in this specification is when the IC is mounted on a 70mm x 70mm x 1.6mm glass epoxy board. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

7. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of GND wiring, and routing of connections.

8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

Operational Notes - continued

11. Regarding Input Pins of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode.

When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

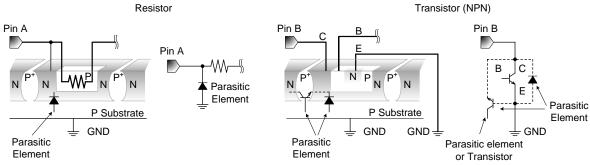


Figure 55. Example of Monolithic IC Structure

12. Unused Circuits

When there are unused circuits it is recommended that they be connected as in Figure 104, setting the non-inverting input terminal to a potential within the in-phase input voltage range (V_{ICM}).

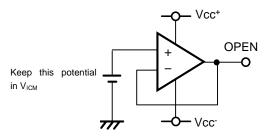


Figure 56. Disable Circuit Example

13. Input Terminal Voltage

Applying Vcc + 36V to the input terminal is possible without causing deterioration of the electrical characteristics or destruction, irrespective of the supply voltage. However, this does not ensure normal circuit operation. Please note that the circuit operates normally only when the input voltage is within the common mode input voltage range of the electric characteristics.

14. Power Supply (signal / dual)

The op-amp operates when the specified voltage supplied is between Vcc⁺ and Vcc⁻. Therefore, the single supply op-amp can be used as a dual supply op-amp as well.

15. Terminal short-circuits

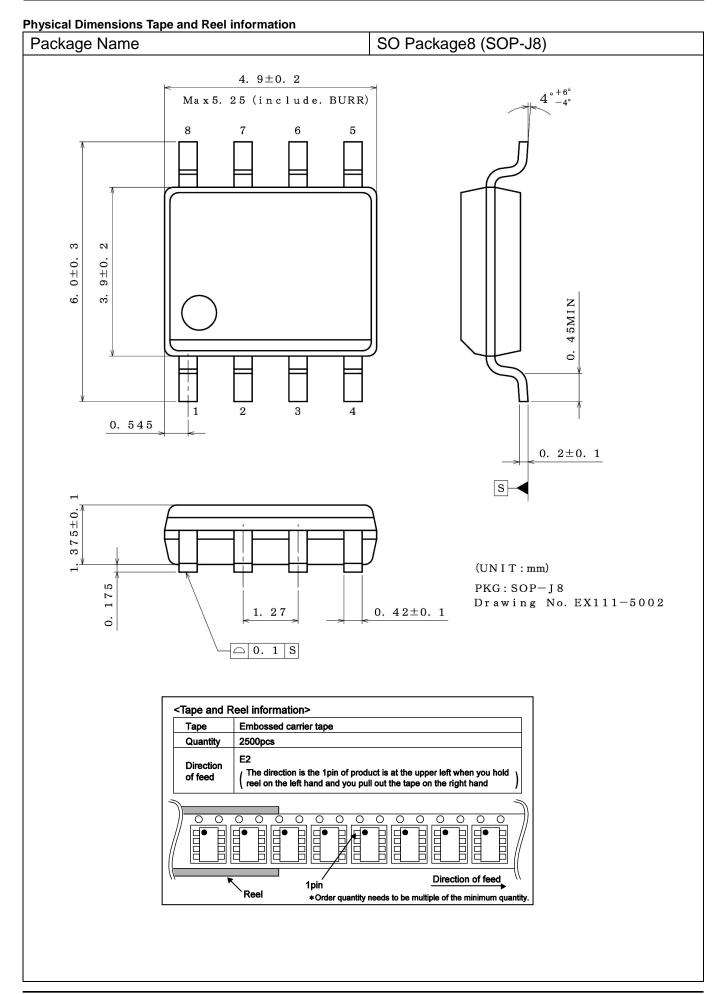
When the output and Vcc⁺ terminals are shorted, excessive output current may flow, resulting in undue heat generation and, subsequently, destruction.

16. IC Handling

Applying mechanical stress to the IC by deflecting or bending the board may cause fluctuations in the electrical characteristics due to piezo resistance effects.

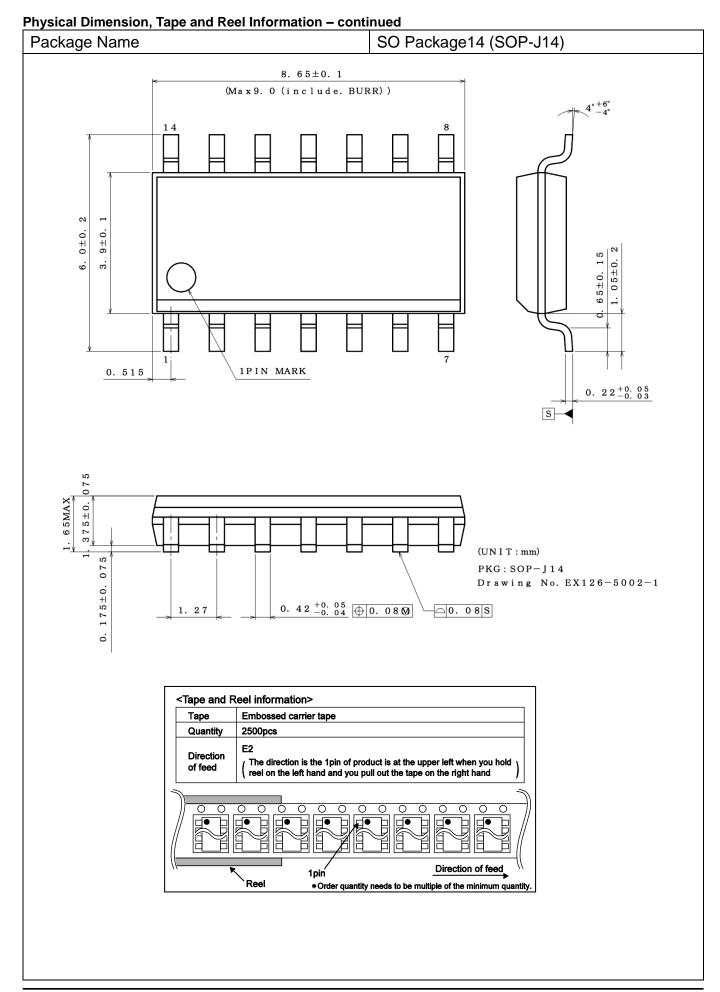
17. Output Capacitor

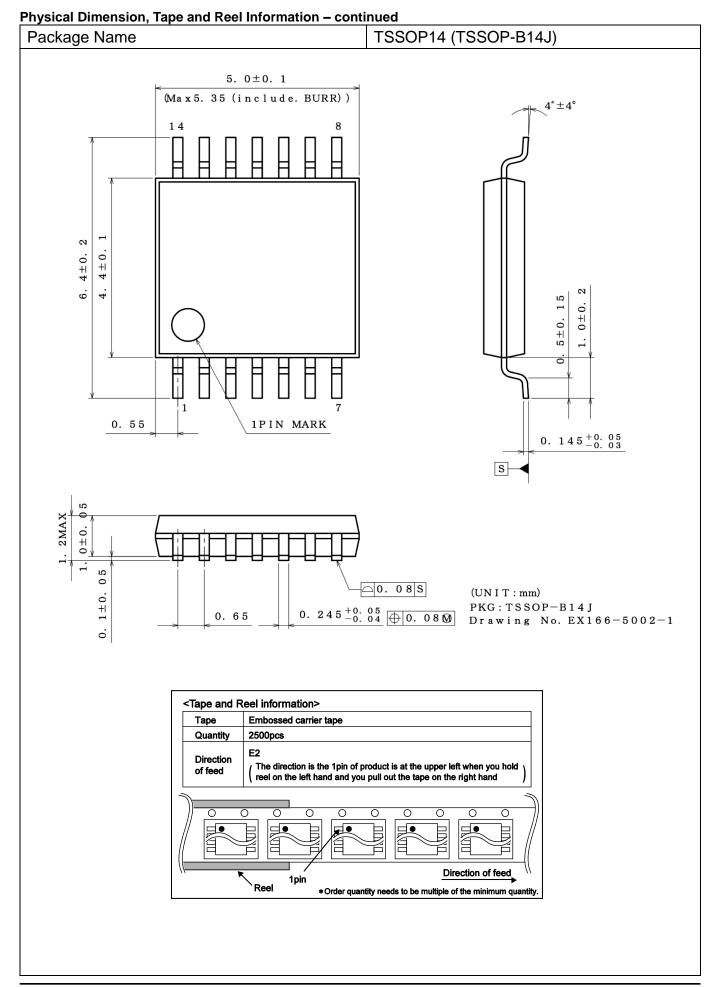
If a large capacitor is connected between the output pin and Vcc⁻ pin, current from the charged capacitor will flow into the output pin and may destroy the IC when the Vcc⁺ pin is shorted to ground or pulled down to 0V. Use a capacitor smaller than 0.1uF between output pin and Vcc⁻ pin.



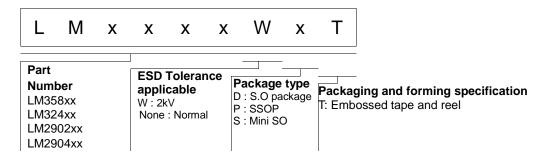
Physical Dimension, Tape and Reel Information - continued Package Name TSSOP8 (TSSOP-B8) 3.0 ± 0.1 $4^{\circ} \pm 4^{\circ}$ (Max3. 35 (include. BURR)) 0. 525 1PIN MARK $0.\ \ 1\ 4\ 5\ ^{+0.\ 0\ 5}_{-0.\ 0\ 3}$ S 1. 2MAX 0.1 ± 0.05 □ 0. 08 S (UN I T: mm) PKG:TSSOP-B8
Drawing No. EX165-5002 0. $245^{+0.05}_{-0.04}$ \bigcirc 0. $08 \bigcirc$ 0.65 <Tape and Reel information> Tape Embossed carrier tape Quantity 3000pcs Direction (The direction is the 1pin of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand of feed Direction of feed Reel *Order quantity needs to be multiple of the minimum quantity.

Physical Dimension, Tape and Reel Information - continued Package Name Mini SO8 (TSSOP-B8J) 3. 0 ± 0 . 1 $4^{\circ} \pm 4^{\circ}$ (Max3. 35 (include. BURR)) 0 ± 0 45 ± 0.15 95 ± 0 o. o, 0. 525 1PIN MARK $0.\ \ 1\ 4\ 5\ ^{+0.\ 0\ 5}_{-0.\ 0\ 3}$ s1. 1MAX $85\pm0.$ 0 5 1 ± 0 . □ 0. 08 S (UN I T: mm) PKG:TSSOP-B8J 0. $32^{+0.05}_{-0.04}$ \bigcirc 0. 080.65 Drawing No. EX164-5002 <Tape and Reel information> Embossed carrier tape Tape 2500pcs Quantity E2 Direction The direction is the 1pin of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand of feed Direction of feed 1pin Reel *Order quantity needs to be multiple of the minimum quantity.





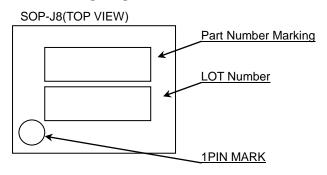
Ordering Information

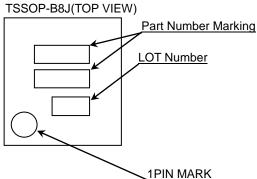


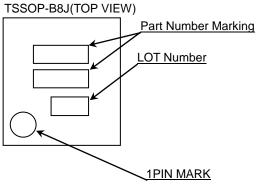
Line-up

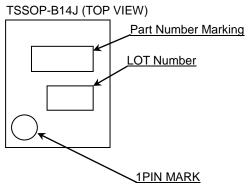
Topr	Dual/Quad	ESD	Package	Orderable Part Number		
			SO Package8 (SOP-J8)	LM358DT		
		Normal	TSSOP8 (TSSPO-B8)	LM358PT		
	Dual		Mini SO8 (TSSOP-B8J)	LM358ST		
-40°C to 85°C		2147	SO Package8 (SOP-J8)	LM358WDT		
		2kV	TSSOP8 (TSSPO-B8)	LM358WPT		
	Quad	Normal	SO Package14 (SOP-J14)	LM324DT		
		Normai	TSSOP14 (TSSOP-B14J)	LM324PT		
		2kV	SO Package14 (SOP-J14)	LM324WDT		
			SO Package8 (SOP-J8)	LM2904DT		
		Normal	TSSOP8 (TSSPO-B8)	LM2904PT		
	Dual		Mini SO8 (TSSOP-B8J)	LM2904ST		
-40°C to +125°C		2kV	SO Package8 (SOP-J8)	LM2904WDT		
-40 C t0 +125 C		ZKV	TSSOP8 (TSSPO-B8)	LM2904WPT		
	_	Normal	SO Package14 (SOP-J14)	LM2902DT		
	Quad	inormal	TSSOP14 (TSSOP-B14J)	LM2902PT		
		2kV	SO Package14 (SOP-J14)	LM2902WDT		

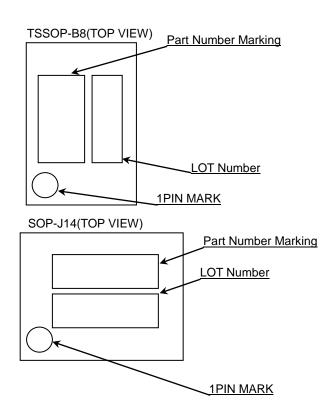
Marking Diagram











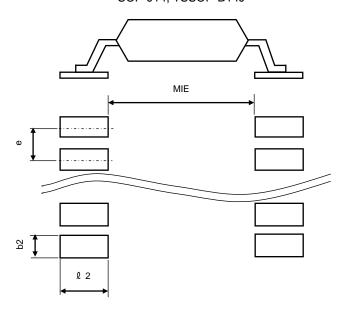
Produc	ct Name	Package Type	Marking
	DT	SO Package8 (SOP-J8)	
	PT	TSSOP8 (TSSPO-B8)]
LM358	ST	Mini SO8 (TSSOP-B8J)	358
	WDT	SO Package8 (SOP-J8)	
	WPT	TSSOP8 (TSSPO-B8)	
	DT	SO Package14 (SOP-J14)	
LM324	PT	TSSOP14 (TSSOP-B14J)	324
	WDT	SO Package14 (SOP-J14)	
	DT	SO Package8 (SOP-J8)	
	PT	TSSOP8 (TSSPO-B8)	
LM2904	ST	Mini SO8 (TSSOP-B8J)	2904
	WDT	SO Package8 (SOP-J8)	
	WPT	TSSOP8 (TSSPO-B8)	
	DT	SO Package14 (SOP-J14)	
LM2902	PT	TSSOP14 (TSSOP-B14J)	2902
	WDT	SO Package14 (SOP-J14)	

Land Pattern Data

All dimensions in mm

PKG	Land pitch e	Land space MIE	Land length ≥{ 2	Land width b2
SO Package8 (SOP-J8) SO Package14 (SOP-J14)	1.27	3.90	1.35	0.76
TSSOP8 (TSSPO-B8) TSSOP14 (TSSOP-B14J)	0.65	4.60	1.20	0.35
Mini SO8 (TSSOP-B8J)	0.65	3.20	1.15	0.35

SOP-J8, TSSOP-B8, TSSOP-B8J, SOP-J14, TSSOP-B14J



Revision History

Date	Revision	Changes
15.Jun.2015	001	New Release

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- 8. Confirm that operation temperature is within the specified range described in the product specification.
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